

Slot/Pre-wired, Wide-width Type (Slot Width: 9.5 mm)

- Photo IC output (Two types available: Dark-ON (EE-SX3160-W11)/ Light-ON (EE-SX4160-W11))
- Featuring enhanced maintainability thanks to a removable dedicated connector
- Mounted with M3 screws
- Wire length 610 mm min. (AWG28)
- Enhanced reliability thanks to solder-less lead wire installation



Be sure to read *Safety Precautions* on Page 3.



Ordering Information

Photomicrosensor

Appearance	Sensing method	Connecting method	Sensing distance	Aperture size (H × W) (mm)	Output type	Model	Minimum packing unit (Unit: pcs)
	Transmissive (slot type)	Pre-wired type	 9.5 mm (Slot width)	Both emitting side and detecting side 1.9 × 1.1	Photo IC	EE-SX3160-W11 (Dark-ON) EE-SX4160-W11 (Light-ON)	1

Note: Order in multiples of minimum packing unit.

Ratings, Characteristics and Exterior Specifications

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value	Unit
Emitter			
Forward current	I _F	50*	mA
Reverse voltage	V _R	4	V
Detector			
Power supply voltage	V _{CC}	16	V
Output voltage	V _{OUT}	28	V
Output current	I _{OUT}	16	mA
Permissible output dissipation	P _{OUT}	250*	mW
Operating temperature	T _{opr}	-25 to 75	°C
Storage temperature	T _{stg}	-25 to 85	°C

* Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

- Note: 1. When screw mounting, use an M3 screw, spring washer, and plain washer and tighten with a torque of 0.5 N·m.
2. Do not use the lead wire with stress applied.

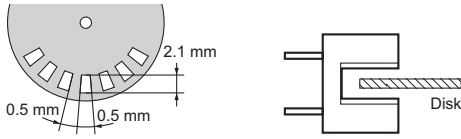
Exterior Specifications

Connecting method	Weight (g)	Material	
		Case	Wire insulator
Pre-wired type	5.05	Polycarbonate	Non-lead PVC

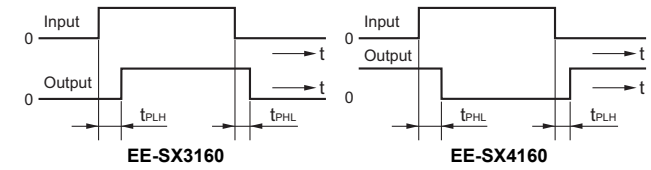
Electrical and Optical Characteristics (Ta = 25°C)

Item	Sym- bol	Value			Unit	Condition
		MIN.	TYP.	MAX.		
Emitter						
Forward voltage	V _F	—	1.2	1.5	V	I _F = 20 mA
Reverse current	I _R	—	0.01	10	μA	V _R = 4 V
Peak emission wavelength	λ _P	—	920	—	nm	I _F = 20 mA
Detector						
Low-level output voltage	V _{OL}	—	0.12	0.4	V	V _{CC} = 4.5 to 16 V, I _{OL} = 16 mA I _F = 0 mA (EE-SX3160) I _F = 10 mA (EE-SX4160)
High-level output voltage	V _{OH}	15	—	—	V	V _{CC} = 16 V, R _L = 1 kΩ I _F = 10 mA (EE-SX3160) I _F = 0 mA (EE-SX4160)
Current consumption	I _{CC}	—	3.2	10	mA	V _{CC} = 16 V
Peak spectral sensitivity wavelength	λ _P	—	870	—	nm	V _{CC} = 4.5 to 16 V
LED current when output OFF (EE-SX3160-W11)	I _{FT}	—	2	10	mA	V _{CC} = 4.5 to 16 V
LED current when output ON (EE-SX4160-W11)						
Hysteresis	ΔH	—	15	—	%	V _{CC} = 4.5 to 16 V*1
Response frequency	f	3	—	—	kHz	V _{CC} = 4.5 to 16 V*2 I _F = 15 mA, I _{OL} = 16 mA
Response delay time	t _{PLH} (t _{PHL})	—	3	—	μs	V _{CC} = 4.5 to 16 V*3 I _F = 15 mA, I _{OL} = 16 mA
Response delay time	t _{PHL} (t _{PLH})	—	20	—	μs	V _{CC} = 4.5 to 16 V*3 I _F = 15 mA, I _{OL} = 16 mA

1. Hysteresis is the difference in LED current between two states when the output state is inverted and expressed as a percentage.
2. The value of the response frequency is measured by rotating the disk as shown below.



3. Refer to the following diagrams for definitions of response delay time. (t_{PHL}) and (t_{PLH}) are applicable to EE-SX4160



Engineering Data (Reference Value) Note: Values in parentheses are for EE-SX4160

Fig 1. Forward Current vs. Temperature

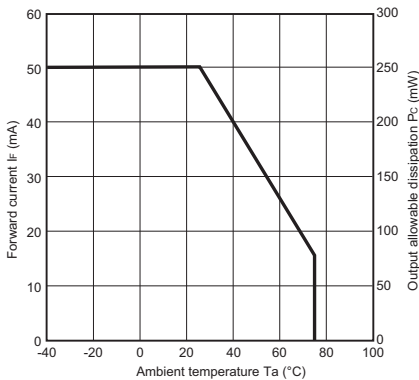


Fig 2. Forward Current vs. Forward Voltage Characteristics (Typical)

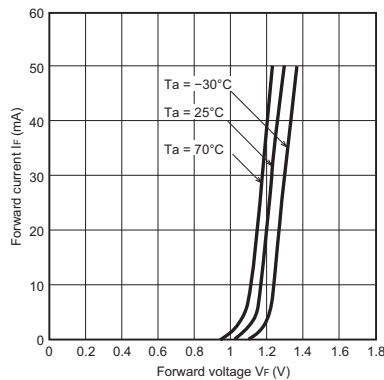


Fig 3. LED Current When Output ON (OFF) vs. Power Supply Voltage Characteristics (Typical)

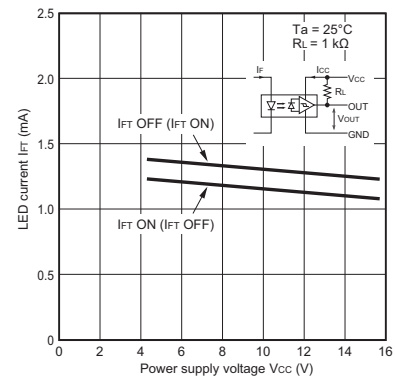


Fig 4. LED Current When Output ON (OFF) vs. Ambient Temperature Characteristics (Typical)

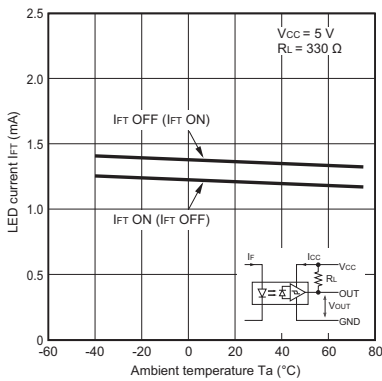


Fig 5. Low-level Output Voltage vs. Output Current Characteristics (Typical)

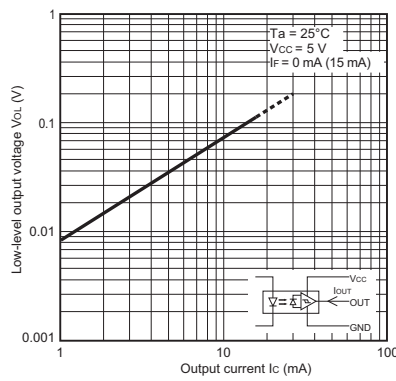


Fig 6. Low-level Output Voltage vs. Ambient Temperature Characteristics (Typical)

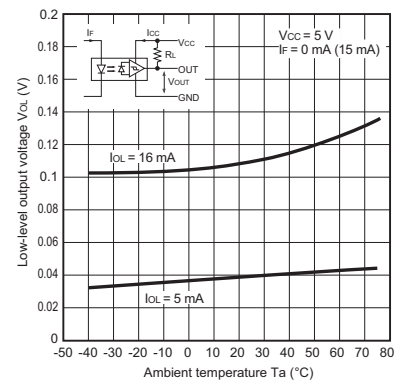


Fig 7. Current Consumption vs. Power Supply Voltage Characteristics (Typical)

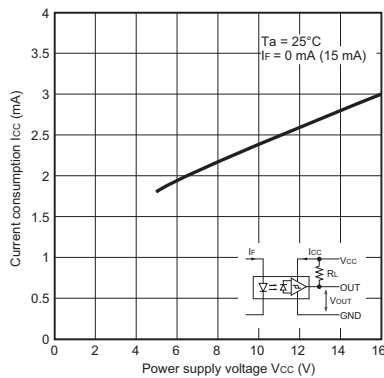


Fig 8. Response Delay Time vs. Forward Current Characteristics (Typical)

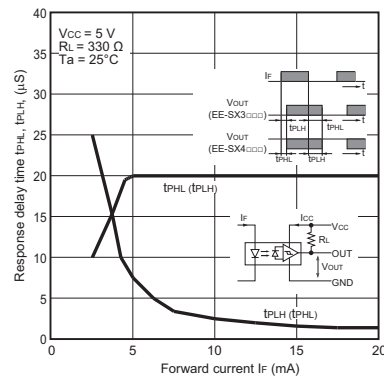
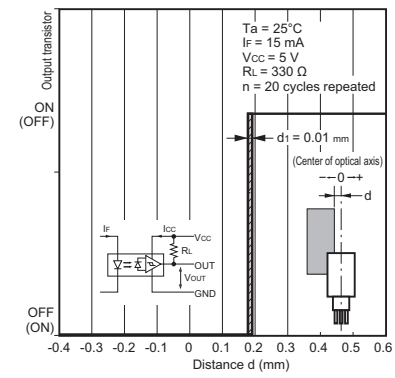


Fig 9. Repeated Sensing Position Characteristics (Typical)



Safety Precautions

To ensure safe operation, be sure to read and follow the Instruction Manual provided with the Sensor.

**CAUTION**

This product is not designed or rated for ensuring safety of persons either directly or indirectly. Do not use it for such purposes.



Precautions for Safe Use

Do not use the product with a voltage or current that exceeds the rated range.
Applying a voltage or current that is higher than the rated range may result in explosion or fire.

Do not miswire such as the polarity of the power supply voltage.
Otherwise the product may be damaged or it may burn.

Do not short-circuit the load.
Otherwise explosion or burning may occur.

This product does not resist water. Do not use the product in places where water or oil may be sprayed onto the product.

Precautions for Correct Use

Do not use the product in atmospheres or environments that exceed product ratings.
When using the sensor on moving parts, secure the pull out portion of the cord so that it is not subjected to direct stress.

Do not perform cord wiring when power supply voltage is applied. Doing so may result in breakage.

Dispose of this product as industrial waste.

Dimensions and Internal Circuit

(Unit: mm)

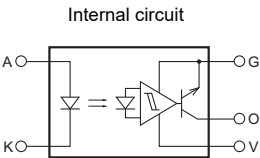
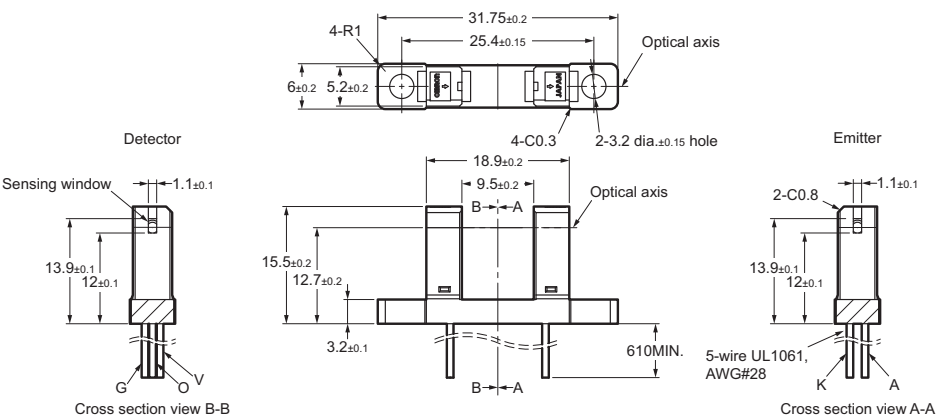
Photomicrosensor

EE-SX3160-W11
EE-SX4160-W11



Aperture size (H × W)

Emitter	Detector
1.9 × 1.1	1.9 × 1.1



Terminal No.	Color	Name
A	Red	Anode
K	Black	Cathode
V	White	Power supply (Vcc)
O	Blue	Output (OUT)
G	Green	Ground (GND)

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

Please check each region's Terms & Conditions by region website.

OMRON Corporation

Device & Module Solutions Company

Regional Contact

Americas

<https://components.omron.com/us>

Asia-Pacific

<https://components.omron.com/ap>

Korea

<https://components.omron.com/kr>

Europe

<https://components.omron.com/eu>

China

<https://components.omron.com.cn>

Japan

<https://components.omron.com/jp>